

GE-312

REPLACES

ECG312

**JFET, N-CH GENERAL
PURPOSE SIL TRANS.**

BVGSS 30V MIN.
IDSS 5-15 MA MIN-MAX
VGS 6V MAX
TRANSCOND. 4000 μ MHOS
PD 300MW
HONG KONG



ALTERNATE
D



BOTTOM VIEW
TO-92

GEM

See your GEM REPLACEMENT SEMICONDUCTOR GUIDE
ELM STATE ELECTRONICS NORTH HAVEN, CT.